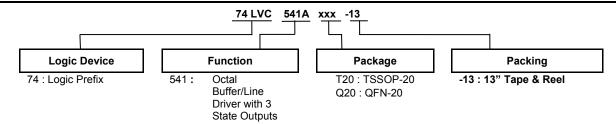


Ordering Information



Dout Number	rt Number Package Package Package Package Size		Package	13" Tape and Reel		
Part Number			Size	Quantity	Part Number Suffix	
74LVC541AT20-13	T20	TSSOP-20	6.4mm X 6.5mm X 1.2mm 0.65 mm lead pitch	2500/Tape & Reel	-13	
74LVC541AQ20-13	Q20	V-QFN4525-20	2.5mm X 4.5mm X 0.95mm 0.50 mm lead pitch	2500/Tape & Reel	-13	

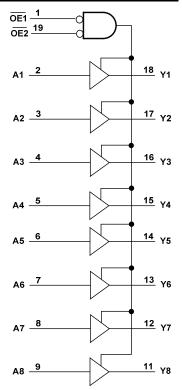
 Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. Notes:

5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm X 2.5mm.

Pin Descriptions

Pin Number	Pin Name	Description
1	OE1	Output Enable 1
2	A1	Data Input
3	A2	Data Input
4	A3	Data Input
5	A4	Data Input
6	A5	Data Input
7	A6	Data Input
8	A7	Data Input
9	A8	Data Input
10	GND	Ground
11	B8	Data Output
12	B7	Data Output
13	B6	Data Output
14	B5	Data Output
15	B4	Data Output
16	B3	Data Output
17	B2	Data Output
18	B1	Data Output
19	OE2	Output Enable 2
20	V _{CC}	Supply Voltage

Logic Diagram



Function Table

	INPUTS		OUTPUT
OE1	OE2	Α	Q
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z



Absolute Maximum Ratings (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK}	Input Clamp Current VI < 0V	-20	mA
I _{OK}	Output Clamp Current V _O < 0V	-50	mA
lo	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	±50	mA
Icc	Continuous Current Through V _{CC}	100	mA
I _{GND}	Continuous Current Through GND	-100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes:

6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range..

Recommended Operating Conditions (Note 8)

Symbol	Parameter	Conditions	Min	Мах	Unit
N/	Supply Voltage	Operating	1.65	3.6	V
V _{CC}	Supply Voltage	Data Retention Only	1.5	—	V
VI	Input Voltage	—	0	5.5	V
Vo	Output Voltage	_	0	V _{CC}	V
		V _{CC} = 1.65V	—	-4	
	High-Level Output Current	V _{CC} = 2.3V	—	-8	
IOH		V _{CC} = 2.7V	—	-12	mA
		V _{CC} = 3.0V	—	-24	
		V _{CC} = 1.65V	—	4	
		V _{CC} = 2.3V	—	8	
IOL	Low-Level Output Current	V _{CC} = 2.7V	—	12	mA
		V _{CC} = 3.0V		24	1
Δt/ΔV	Input Transition Rise or Fall Rate		_	10	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 8. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics

Symphol	Parameter	Test Conditions	N/			T _A = -40°C	to +125°C	Unit	
Symbol	Farameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit	
			1.65V to 1.95V	V _{CC} X 0.65	—	V _{CC} X 0.65	_		
V _{IH}	High-Level Input Voltage		2.3V to 2.7V	1.7	_	1.7	—	V	
	Vollage		3.0V to 3.6V	2	—	2	—		
			1.65V to 1.95V	—	V _{CC} X 0.35	_	V _{CC} X 0.35		
VIL	Low-Level input voltage		2.3V to 2.7V	—	0.7	—	0.7	V	
	Vollago		3.0V to 3.6V	—	0.8	—	0.8		
		I _{OH} = -50μA	1.65V to 3.6V	V _{CC} -0.2	—	V _{CC} -0.3	—		
		I _{OH} = -4mA	1.65V	1.2	—	1.05	_		
V	High-Level	I _{OH} = -8mA	2.3V	1.7	_	1.65	_		
V _{OH}	Output Voltage	10	2.7V	2.2	_	2.05	_	v	
			I _{OH} = -12mA	3.0V	2.4	_	2.48	_	v
		I _{OH} = -24mA	3.0V	2.3	—	2.0	—		
		I _{OL} = 100μΑ	1.65V to 3.6V		0.2	_	0.3		
	Low-Level Output Voltage	I _{OL} = 4mA	1.65V		0.45	_	0.65	v	
V _{OL}		I _{OL} = 8mA	2.3V	_	0.60	_	0.80		
		$I_{OL} = 12mA$		_	0.40	_	0.60		
		I _{OL} = 24mA	3.0V	_	0.55	_	0.80		
I _{OFF}	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O}$ = 0 or 5.5V	0V	_	±10	—	20	μA	
lı	Input Current Control Pins	V ₁ = GND or 5.5V	0 to 3.6V	_	±5	_	±20	μA	
I _{OZ}	Z-State Current including Input Current I/O Pins	V _I = GND or 5.5V V _O = 0 to 5.5V	3.6V	_	±5	_	±20	μA	
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}, I_{O} = 0$	3.6V	—	10	—	40	μA	
ΔI_{CC}	Additional Supply Current	One Input at V _{CC} -0.6V I _O = 0A	2.7V to 3.6V	—	500	_	5000	μA	
Ci	Input Capacitance	$\frac{\text{Control Pins}}{I/O \text{Pins}} V_{I} = \text{GND or } V_{CC}$	$V_{i} = GND \text{ or } V_{cc} = 0V \text{ to } 3.6V$		/pical /pical	pF			

Switching Characteristics

Symbol	Parameter	Test	Vaa	-	T _A = +25°0	;	T _A = -40°	C to +85°C	T _A = -40°	°C to +125°C	Unit
Symbol	Falameter	Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	_		1.8V ± 0.15V	1	6.0	13.2	1	17.7	1	18.9	
	Propagation	Figure 1	2.5V ± 0.2 V	1	3.9	8.6	1	9.6	1	10.7	
t _{PD}	Delay A_N to Y_N	Figure 1	2.7V	1	4.2	7.5	1	7.9	1	9.5	ns
			3.3V ± 0.3V	1.5	3.8	6.5	1.5	6.9	1.5	8.8	
	Enable Time \overline{OE} to Y_N		1.8V ± 0.15V	1	7	14.8	1	17.5	1	18.5	
			2.5V ± 0.2V	1	4.5	13	1	16.5	1	17.5	
t _{EN}		Figure 1	2.7V	1	5.4	8.3	1	7.5	1	11.5	ns
			3.3V ± 0.3V	1.5	4.4	6.4	1.5	7.0	1.5	8.0	
			1.8V ± 0.15V	1	7.8	15.5	1	16.5	1	18.2	
	Disable Time	Figure 1	2.5V ± 0.2V	1	5	8.7	1	9.0	1	9.6	
t _{DIS}	\overline{OE} to Y_N	Figure 1	2.7V	1	4.4	7.5	1	7.7	1	10.0	ns
			3.3V ± 0.3V	1.7	4.1	6.9	1.7	7.0	1.7	9.0	
t _{sk(0)}	Output Skew Time		3.3V ± 0.3V			1.0				1.5	ns

NEW PRODUCT



Operating Characteristics

Symbol	Parameter	Test Conditions	Vcc	Тур	Unit	
C _{pd}	Davida dia sia stisa		1.8V ± 0.15V	9.9		
	Power dissipation capacitance per gate	F = 10 MHz	2.5V ± 0.2V	10.2	pF	
			3.3V ± 0.3V	10.6		

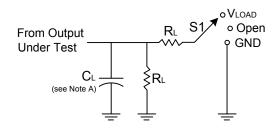
Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
θ _{JA}	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 9)	_	74	_	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 9)	_	15	_	°C/W
θ _{JA}	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 9)	_	67	_	°C/W
θ_{JC}	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 9)	_	20	_	°C/W

Note: 9. Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.



Parameter Measurement Information

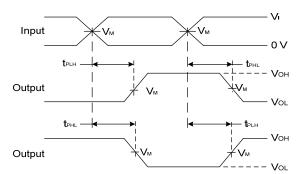


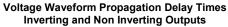
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

V	Inputs		V	V	C	Р	MA	
Vcc	VI	t _r /t _f	V _M	V _{LOAD}	CL	RL	VΔ	
1.8V ± 0.15V	V _{CC}	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	1ΚΩ	0.15V	
2.5V ± 0.2V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	500Ω	0.15V	
2.7V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	
3.3V ± 0.3V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	



Voltage Waveform Pulse Duration

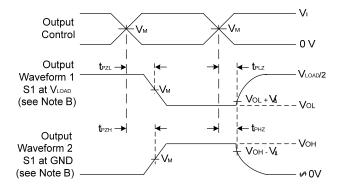




Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
 C. Inputs are measured separately one transition per measurement.
- D. t_{PLZ} and t_{PHZ} are the same as t_{dis} . E. t_{PZL} and t_{PZH} are the same as t_{ENO}
- F. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1 Load Circuit and Voltage Waveforms

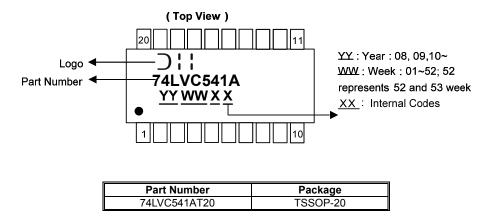


Voltage Waveform Enable and Disable Times Low and High Level Enabling

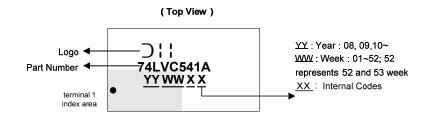


Marking Information

(1) TSSOP20



(2) QFN-20 (V-QFN4525-20)



Part Number	Package
74LVC541AQ20	V-QFN4525-20

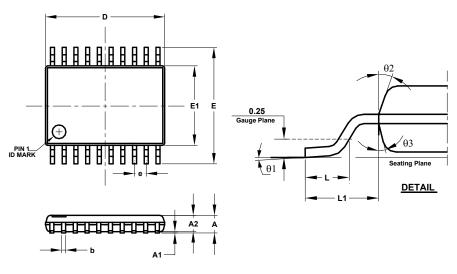


Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

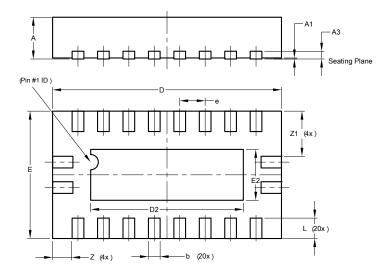
(1) TSSOP-20

NEW PRODUCT



TSSOP-20				
Dim	Min	Max	Тур	
Α	-	1.20	-	
A1	0.05	0.15	-	
A2	0.80	1.05	-	
b	0.19	0.30	-	
С	0.09	0.20	-	
D	6.40	6.60	6.50	
E	6.20	6.60	6.40	
E1	4.30	4.50	4.40	
е	0.65 BSC			
L	0.45	0.75	0.60	
L1	1.0 REF			
θ1	0°	8°	-	
θ2	10°	14°	12°	
θ3	10°	14°	12°	
All Dimensions in mm				

(2) QFN-20 (V-QFN4525-20)



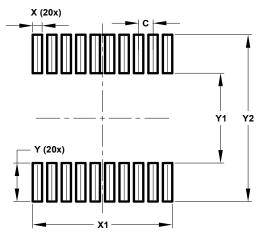
V-QFN4525-20				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05	0.02	
A3	-	-	0.15	
b	0.18	0.30	0.23	
D	4.45	4.55	4.50	
D2	2.85	3.15	3.00	
E	2.45	2.55	2.50	
E2	0.85	1.15	1.00	
е	0.50BSC			
L	0.30	0.50	0.40	
Z	-	-	0.385	
Z1	-	-	0.885	
All Dimensions in mm				



Suggested Pad Layout

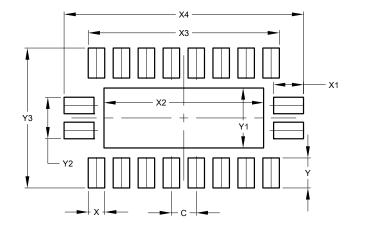
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) TSSOP-20



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	6.270
Y	1.789
Y1	4.160
Y2	7.720

(2) QFN-20 (V-QFN4525-20)



Dimensions	Value (in mm)
С	0.500
Х	0.330
X1	0.600
X2	3.200
X3	3.830
X4	4.800
Y	0.600
Y1	1.200
Y2	0.830
Y3	2.800

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